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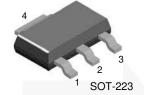


January 2014

# NZT660 / NZT660A PNP Low Saturation Transistor

## **Description**

These devices are designed with high-current gain and low saturation voltage with collector currents up to 3 A continuous.



1. Base 2,4. Collector 3. Emitter

## **Ordering Information**

| Part Number | Marking | Package    | Packing Method |
|-------------|---------|------------|----------------|
| NZT660      | 660     | SOT-223 4L | Tape and Reel  |
| NZT660A     | 660A    | SOT-223 4L | Tape and Reel  |

## **Absolute Maximum Ratings**(1),(2)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at Values are at  $T_A = 25^{\circ}$ C unless otherwise noted.

| Symbol                            | Parameter  | Val         | Unit        |    |
|-----------------------------------|--|-------------|-------------|----|
|                                   | r at attletet                                    | NZT660      | NZT660A     |    |
| V <sub>CEO</sub>                  | Collector-Emitter Voltage                        | -60         | -60         | V  |
| V <sub>CBO</sub>                  | Collector-Base Voltage                           | -80         | -60         | V  |
| V <sub>EBO</sub>                  | Emitter-Base Voltage                             | -5          | -5          | V  |
| I <sub>C</sub>                    | Collector Current - Continuous                   | -3          | -3          | Α  |
| T <sub>J</sub> , T <sub>STG</sub> | Operating and Storage Junction Temperature Range | -55 to +150 | -55 to +150 | °C |

#### Notes:

- 1. These ratings are based on a maximum junction temperature of 150°C.
- 2. These are steady state limits. Fairchild Semiconductor should be consulted on application involving pulsed or low-duty cycle operation.

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## Thermal Characteristics(3)

Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

| Symbol          | Parameter                               | Max. | Unit |
|-----------------|---|------|------|
| P <sub>D</sub>  | Total Device Dissipation                | 2    | W    |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 62.5 | °C/W |

#### Note:

3. PCB size: FR-4 76 x 114 x 1.57  $\text{mm}^3$  (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

## **Electrical Characteristics**

Values are at  $T_A = 25^{\circ}\text{C}$  unless otherwise noted.

| Symbol                | Parameter Conditions   |  | Min.    | Max. | Unit  |     |
|-----------------------|--|--|---------|------|-------|-----|
| BV <sub>CEO</sub>     | Collector-Emitter Breakdown<br>Voltage   | I <sub>C</sub> = -10 mA  |         | -60  |       | V   |
| BV.                   | Collector Raco Broakdown Voltago   | $I_0 = -100  \mu A$  | NZT660  | -80  |       | V   |
| BV <sub>CBO</sub>     | Collector-Base Breakdown Voltage   |  | NZT660A | -60  |       |     |
| BV <sub>EBO</sub>     | Emitter-Base Breakdown Voltage   | I <sub>E</sub> = -100 μA   |         | -5   |       | V   |
| /1                    | Collector Race Cut Off Current   | V <sub>CB</sub> = -30 V  |         |      | -100  | nA  |
| I <sub>CBO</sub>      | Collector-Base Cut-Off Current   | V <sub>CB</sub> = -30 V, T <sub>A</sub> = 100°C                  |         |      | -10   | μΑ  |
| I <sub>EBO</sub>      | Emitter-Base Cut-Off Current   | V <sub>EB</sub> = -4 V   |         |      | -100  | nA  |
|                       |  | $I_C = -100 \text{ mA}, V_{CE} = -2$                             | V       | 70   |       |     |
|                       | DC Current Gain <sup>(4)</sup>   | I <sub>C</sub> = -500 mA, V <sub>CE</sub> = -2 V                 | NZT660  | 100  | 300   |     |
| h <sub>FE</sub>       |  |  | NZT660A | 250  | 550   |     |
|                       |  | I <sub>C</sub> = -1 A, V <sub>CE</sub> = -2 V                    |         | 80   |       |     |
|                       |  | I <sub>C</sub> = -3 A, V <sub>CE</sub> = -2 V                    |         | 25   |       |     |
|                       | Collector-Emitter Saturation Voltage <sup>(4)</sup>                                | $I_C = -1 \text{ A}, I_B = -100 \text{ mV}$                      |         |      | -300  |     |
|                       |  | $I_{C} = -3 \text{ A. } I_{D} = -300 \text{ mV}$                 | NZT660  |      | -550  | mV  |
|                       |  |  | NZT660A | -/   | -500  |     |
| V <sub>BE</sub> (sat) | Base-Emitter Saturation Voltage <sup>(4)</sup>                                     | I <sub>C</sub> = -1 A, I <sub>B</sub> = -100 mV                  |         |      | -1.25 | V   |
| V <sub>BE</sub> (on)  | Base-Emitter On Voltage <sup>(4)</sup> $I_C = -1 \text{ A}, V_{CE} = -2 \text{ V}$ |  |         | -1   | V     |     |
| C <sub>ob</sub>       | Output Capacitance   | V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0, f = 1 MHz           |         |      | 45    | pF  |
| f <sub>T</sub>        | Transition Frequency   | I <sub>C</sub> = -100 mA, V <sub>CE</sub> = -5 V,<br>f = 100 MHz |         | 75   |       | MHz |

## Note:

4. Pulse test: pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2.0%.

## **Typical Performance Characteristics**

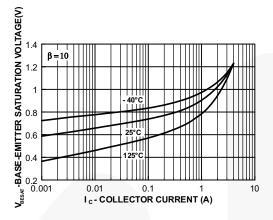


Figure 1. Base-Emitter Saturation Voltage vs. Collector Current

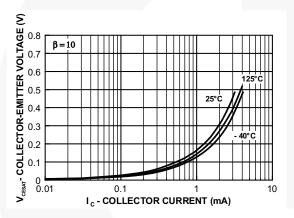


Figure 3. Collector-Emitter Saturation Voltage vs. Collector Current

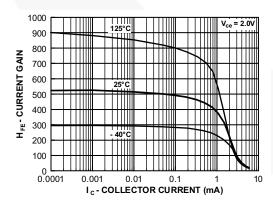


Figure 5. Current Gain vs. Collector Current

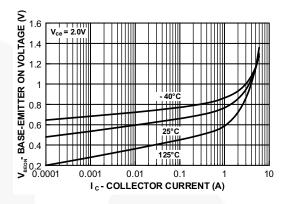


Figure 2. Base-Emitter On Voltage vs. Collector Current

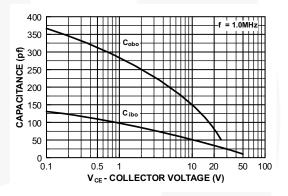


Figure 4. Input / Output Capacitance vs. Reverse Bias Voltage

## **Physical Dimensions**

## **SOT-223**

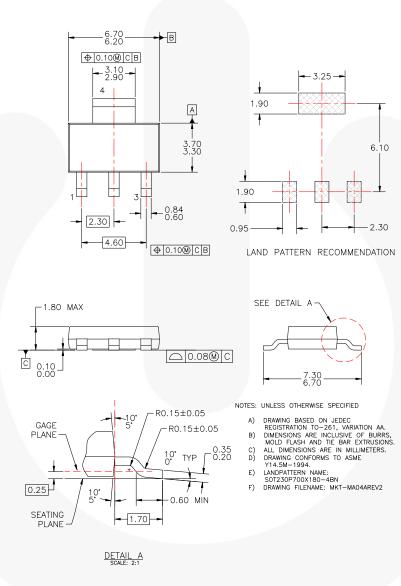


Figure 6. MOLDED PACKAGE, SOT-223, 4 LEAD (ACTIVE)

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